

Functional hybrid inorganic-organic systems(HIOSs)

- Molecular thin films on inorganic substrates material have critical applications : organic solar cells (OSCs), organic field effect transistors (OFETs), organic light emitting diodes (OLEDs) and sensors.
- Understanding the structure and electronic properties of HIOSs is key to enhance the performance of organic electronic devices. The interfacial structure directly affects properties through changes in the intermolecular electronic coupling, dipole formation, polarization induced gap narrowing, and charge transfer (CT).

Experimental characterization & Limitation

- Experimental characterization of HIOSs is performed through surface science techniques: topographic surface imaging (STM), spectroscopy (UPS), surface scattering (NIXSW), and thermodynamic measurements ((TPD)).
- Limitation: indirect information like spectra, hard to directly associate with geometry. The exact adsorption site is undetermined

Computational study

- Complement spectroscopy experiments by assigning the observed spectral features to specific atomic configurations and electronic state
- Access the vast configuration space of possible interface structures and compositions and explore materials that have not been made yet
- Help determine the energetically most favored adsorption site





Figure 1. An example of potential energy surface(PES)¹(left). Different absorption sites of naphthalene molecule on Cu(111)²(right).

Genarris 4.0

- A random structure generator for organic/inorganic interfaces
- Genarris 4.0 is written in python and interface with FHI-aims
- for interface energy evaluation and geometry relaxation.
- 1st step: film lattice generation



